

P-Channel Enhancement Mode Power MOSFET

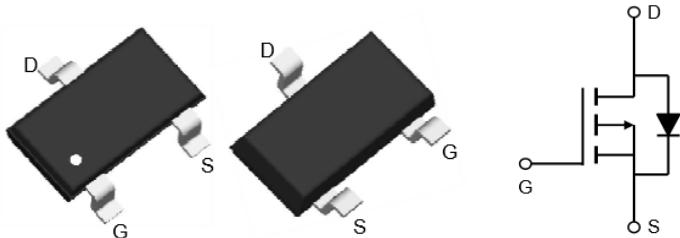
- Features

$V_{DS} = -30V$,
 $I_D = -4.3A$
 $R_{DS(ON)} @ V_{GS} = -10V, TYP 45m\Omega$
 $R_{DS(ON)} @ V_{GS} = -4.5V, TYP 67m\Omega$

- General Description

- Power Management in Notebook Computer
- Portable Equipment and Battery Powered Systems

- Pin Configurations



SOT-23

- Absolute Maximum Ratings @ $T_A=25^\circ C$ unless otherwise noted

Parameter		Symbol	Ratings	Unit
Drain-Source Voltage		V_{DSS}	-30	V
Gate-Source Voltage		V_{GSS}	± 20	V
Drain Current (Continuous) *AC	$T_A=25^\circ C$	I_D	-4.3	A
	$T_A=70^\circ C$		-3	
Drain Current (Pulse) *B		I_{DM}	-15.2	A
Power Dissipation	$T_A=25^\circ C$	P_D	1.25	W
Operating Temperature/ Storage Temperature		T_J/T_{STG}	-55~150	°C

- Thermal Resistance Ratings

Parameter	Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient	$t \leq 5s$	R_{thJA}	80	°C/W

● **Electrical Characteristics** @ $T_A=25^\circ C$ unless otherwise noted

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Static *D						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = -250\mu A$	-30	--	--	V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = -30V, V_{GS} = 0V$	--	--	-1	μA
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{GS} = V_{DS}, I_{DS} = -250\mu A$	-1	-1.5	-3	V
Gate Leakage Current	I_{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$	--	--	± 100	nA
Drain-Source On-state Resistance	$R_{DS(on)}$	$V_{GS} = -10V, I_D = -4.3A$	--	45	63	$m\Omega$
	$R_{DS(on)}$	$V_{GS} = -4.5V, I_D = -3A$	--	67	87	$m\Omega$
Diode Forward Voltage	V_{SD}	$I_{SD} = -1A, V_{GS} = 0V$	--	-0.73	-1.2	V
Diode Forward Current *AC	I_s	$T_A = 25^\circ C$	--	--	-1.7	A
Switching						
Total Gate Charge	Q_g	$V_{GS} = -10V, V_{DS} = -15V, I_D = -3.8A$	--	13	--	nC
Gate-Source Charge	Q_{gs}		--	2	--	nC
Gate-Drain Charge	Q_{gd}		--	3	--	nC
Turn-on Delay Time	$t_{d(on)}$	$V_{DD} = -15V, R_G = 6\Omega, I_D = -1A, V_{GS} = -10V$	--	11	--	ns
Turn-on Rise Time	t_r		--	5	--	ns
Turn-off Delay Time	$t_{d(off)}$		--	30	--	ns
Turn-Off Fall Time	t_f		--	7	--	ns
Dynamic						
Input Capacitance	C_{iss}	$V_{GS} = 0V, V_{DS} = -15V, f = 1.0MHz$	--	640	--	pF
Output Capacitance	C_{oss}		--	130	--	pF
Reverse Transfer Capacitance	C_{rss}		--	95	--	pF

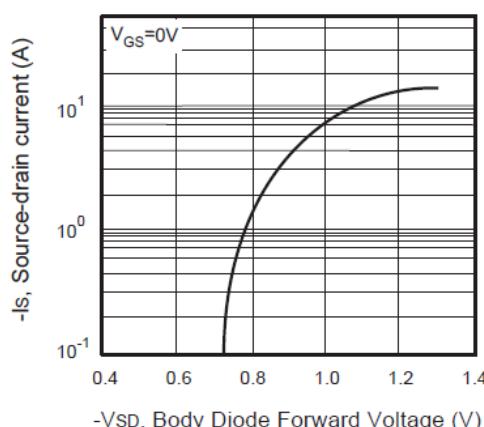
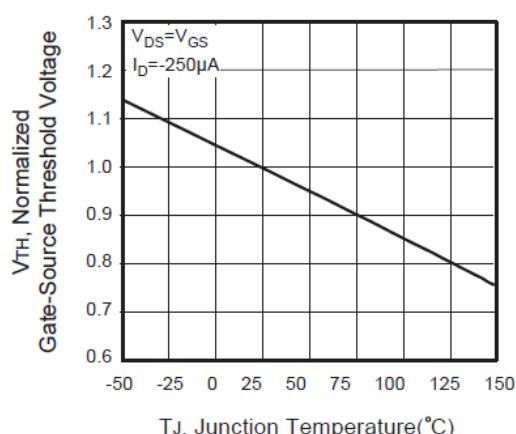
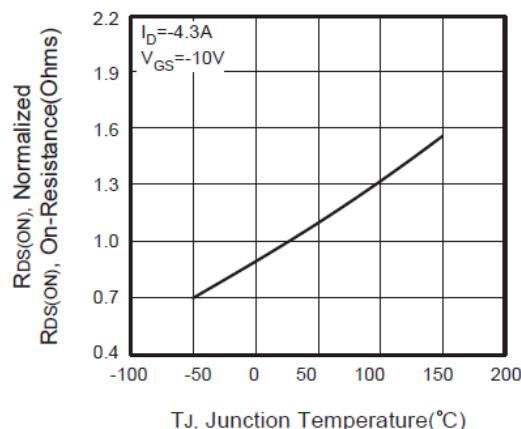
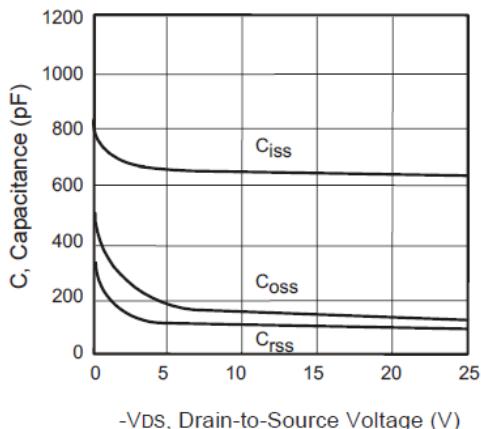
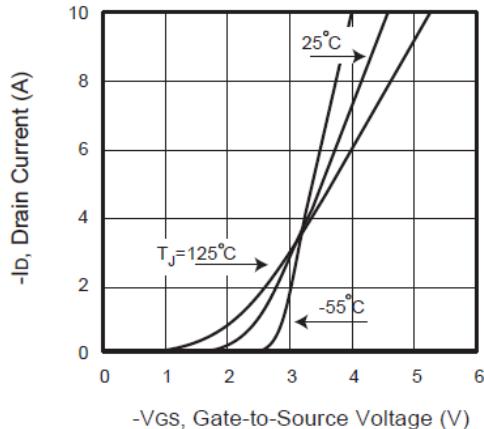
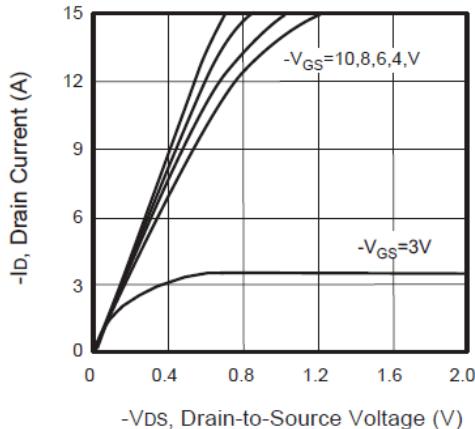
A: The value of $R_{\theta JA}$ is measured with the device mounted on 1in² FR-4 board with 2oz. Copper, in a still air environment with $T_A=25^\circ C$. The value in any given application depends on the user's specific board design.

B: Repetitive rating, pulse width limited by junction temperature.

C: The current rating is based on the $t \leq 10s$ junction to ambient thermal resistance rating.

D: Pulse Test: Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2\%$.

- **Typical Performance Characteristics** (($T_J = 25^\circ\text{C}$, unless otherwise noted))



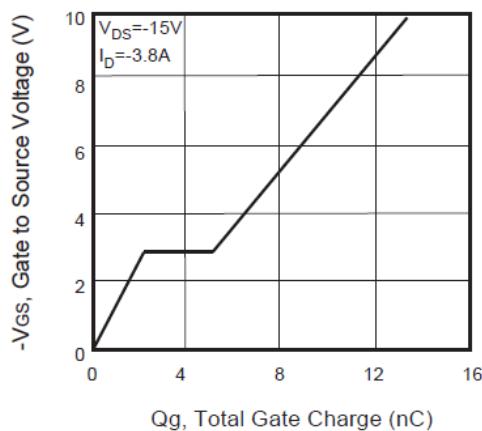


Figure 7. Gate Charge

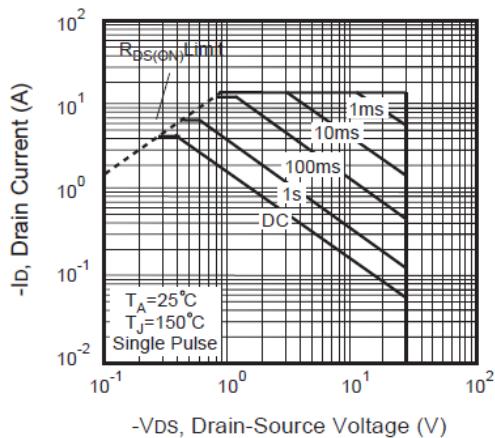


Figure 8. Maximum Safe Operating Area

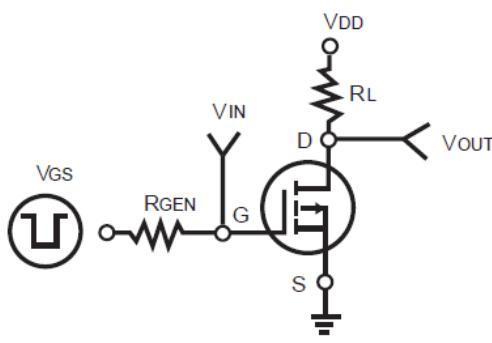


Figure 9. Switching Test Circuit

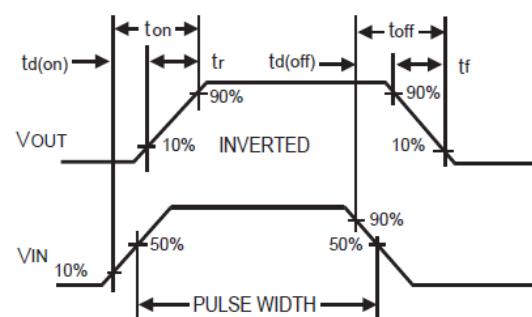


Figure 10. Switching Waveforms

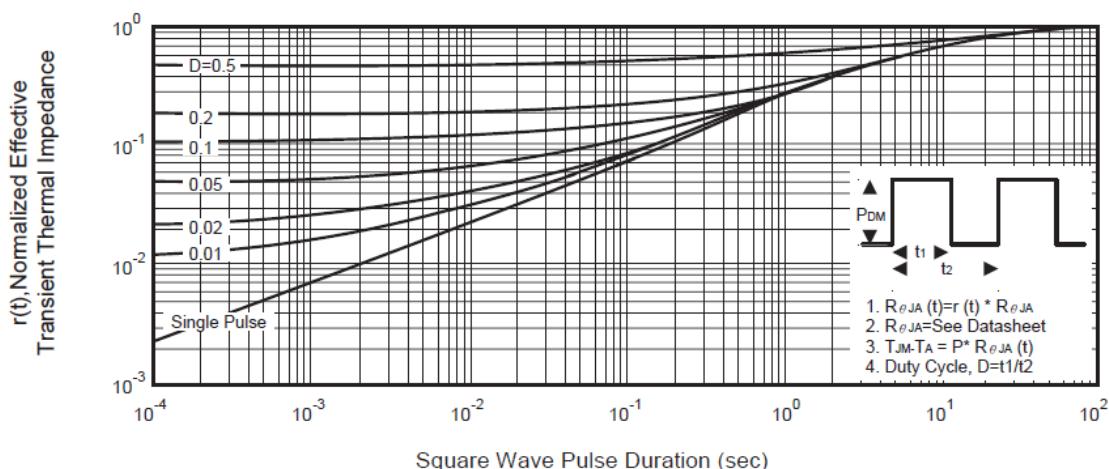
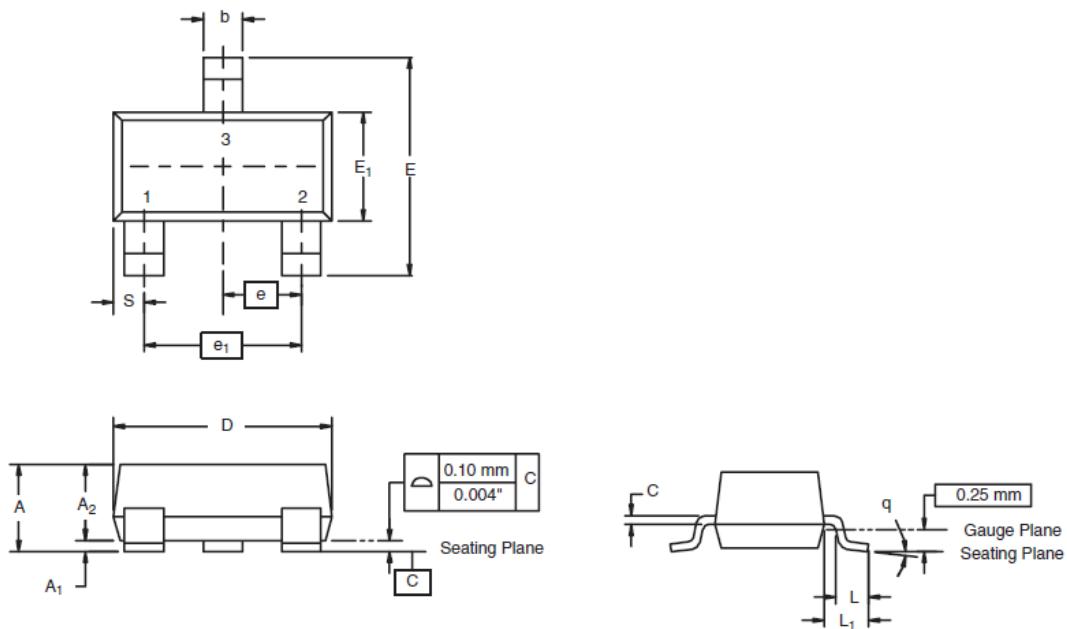


Figure 11. Normalized Thermal Transient Impedance Curve

● Package Information



Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	0.89	1.12	0.035	0.044
A ₁	0.01	0.10	0.0004	0.004
A ₂	0.88	1.02	0.0346	0.040
b	0.35	0.50	0.014	0.020
c	0.085	0.18	0.003	0.007
D	2.80	3.04	0.110	0.120
E	2.10	2.64	0.083	0.104
E ₁	1.20	1.40	0.047	0.055
e	0.95 BSC		0.0374 Ref	
e ₁	1.90 BSC		0.0748 Ref	
L	0.40	0.60	0.016	0.024
L ₁	0.64 Ref		0.025 Ref	
S	0.50 Ref		0.020 Ref	
q	3°	8°	3°	8°

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